

## Medium Power Phase Control Thyristors (Stud Version), 16 A



TO-208AA (TO-48)

### FEATURES

- Improved glass passivation for high reliability and exceptional stability at high temperature
- High  $di/dt$  and  $dV/dt$  capabilities
- Standard package
- Low thermal resistance
- Metric threads version available
- Types up to 1200 V  $V_{DRM}/V_{RRM}$
- Designed and qualified for industrial and consumer level
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


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COMPLIANT

### TYPICAL APPLICATIONS

- Medium power switching
- Phase control applications
- Can be supplied to meet stringent military, aerospace and other high reliability requirements

### PRODUCT SUMMARY

|                   |                   |
|-------------------|-------------------|
| Package           | TO-48 (TO-208AA)  |
| Diode variation   | Single SCR        |
| $I_{T(AV)}$       | 16 A              |
| $V_{DRM}/V_{RRM}$ | 100 V to 1200 V   |
| $V_{TM}$          | 1.75 V            |
| $I_{GT}$          | 60 mA             |
| $T_J$             | - 65 °C to 125 °C |

### MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER         | TEST CONDITIONS | VALUES      | UNITS            |
|-------------------|-----------------|-------------|------------------|
| $I_{T(AV)}$       |                 | 16          | A                |
|                   | $T_C$           | 85          | °C               |
| $I_{T(RMS)}$      |                 | 35          | A                |
| $I_{TSM}$         | 50 Hz           | 340         | A                |
|                   | 60 Hz           | 360         |                  |
| $I^2t$            | 50 Hz           | 574         | A <sup>2</sup> s |
|                   | 60 Hz           | 524         |                  |
| $V_{DRM}/V_{RRM}$ |                 | 100 to 1200 | V                |
| $t_q$             | Typical         | 110         | µs               |
| $T_J$             |                 | - 65 to 125 | °C               |

### ELECTRICAL SPECIFICATIONS

#### VOLTAGE RATINGS

| TYPE NUMBER | VOLTAGE CODE | $V_{DRM}/V_{RRM}$ , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE <sup>(1)</sup><br>V | $V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK VOLTAGE <sup>(2)</sup><br>V | $I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM<br>mA |
|-------------|--------------|---------------------------------------------------------------------------------------|---------------------------------------------------------------------|--------------------------------------------------------|
| 16RIA       | 10           | 100                                                                                   | 150                                                                 | 20                                                     |
|             | 20           | 200                                                                                   | 300                                                                 | 10                                                     |
|             | 40           | 400                                                                                   | 500                                                                 |                                                        |
|             | 60           | 600                                                                                   | 700                                                                 |                                                        |
|             | 80           | 800                                                                                   | 900                                                                 |                                                        |
|             | 100          | 1000                                                                                  | 1100                                                                |                                                        |
|             | 120          | 1200                                                                                  | 1300                                                                |                                                        |

#### Notes

<sup>(1)</sup> Units may be broken over non-repetitively in the off-state direction without damage, if  $di/dt$  does not exceed 20 A/µs

<sup>(2)</sup> For voltage pulses with  $t_p \leq 5$  ms

**ABSOLUTE MAXIMUM RATINGS**

| PARAMETER                                            | SYMBOL              | TEST CONDITIONS                                                                                           |                                  |                                                                       | VALUES | UNITS             |
|------------------------------------------------------|---------------------|-----------------------------------------------------------------------------------------------------------|----------------------------------|-----------------------------------------------------------------------|--------|-------------------|
| Maximum average on-state current at case temperature | I <sub>T(AV)</sub>  | 180° sinusoidal conduction                                                                                |                                  |                                                                       | 16     | A                 |
|                                                      |                     |                                                                                                           |                                  |                                                                       | 85     | °C                |
| Maximum RMS on-state current                         | I <sub>T(RMS)</sub> |                                                                                                           |                                  |                                                                       | 35     | A                 |
| Maximum peak, one-cycle non-repetitive surge current | I <sub>TSM</sub>    | t = 10 ms                                                                                                 | No voltage reapplied             | Sinusoidal half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum | 340    | A                 |
|                                                      |                     | t = 8.3 ms                                                                                                |                                  |                                                                       | 360    |                   |
|                                                      |                     | t = 10 ms                                                                                                 | 100 % V <sub>RRM</sub> reapplied |                                                                       | 285    |                   |
|                                                      |                     | t = 8.3 ms                                                                                                |                                  |                                                                       | 300    |                   |
| Maximum I <sup>2</sup> t for fusing                  | I <sup>2</sup> t    | t = 10 ms                                                                                                 | No voltage reapplied             |                                                                       | 574    | A <sup>2</sup> s  |
|                                                      |                     | t = 8.3 ms                                                                                                |                                  |                                                                       | 524    |                   |
|                                                      |                     | t = 10 ms                                                                                                 | 100 % V <sub>RRM</sub> reapplied |                                                                       | 405    |                   |
|                                                      |                     | t = 8.3 ms                                                                                                |                                  |                                                                       | 375    |                   |
| Maximum I <sup>2</sup> √t for fusing                 | I <sup>2</sup> √t   | t = 0.1 to 10 ms, no voltage reapplied, T <sub>J</sub> = T <sub>J</sub> maximum                           |                                  |                                                                       | 5740   | A <sup>2</sup> √s |
| Low level value of threshold voltage                 | V <sub>T(TO)1</sub> | (16.7 % × π × I <sub>T(AV)</sub> ) < I < π × I <sub>T(AV)</sub> , T <sub>J</sub> = T <sub>J</sub> maximum |                                  |                                                                       | 0.97   | V                 |
| High level value of threshold voltage                | V <sub>T(TO)2</sub> | (I > π × I <sub>T(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum                                    |                                  |                                                                       | 1.24   |                   |
| Low level value of on-state slope resistance         | r <sub>t1</sub>     | (16.7 % × π × I <sub>T(AV)</sub> ) < I < π × I <sub>T(AV)</sub> , T <sub>J</sub> = T <sub>J</sub> maximum |                                  |                                                                       | 17.9   | mΩ                |
| High level value of on-state slope resistance        | r <sub>t2</sub>     | (I > π × I <sub>T(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum                                    |                                  |                                                                       | 13.6   |                   |
| Maximum on-state voltage                             | V <sub>TM</sub>     | I <sub>pk</sub> = 50 A, T <sub>J</sub> = 25 °C                                                            |                                  |                                                                       | 1.75   | V                 |
| Maximum holding current                              | I <sub>H</sub>      | T <sub>J</sub> = 25 °C, anode supply 6 V, resistive load                                                  |                                  |                                                                       | 130    | mA                |
| Latching current                                     | I <sub>L</sub>      |                                                                                                           |                                  |                                                                       | 200    |                   |

**SWITCHING**

| PARAMETER                                 | SYMBOL                       | TEST CONDITIONS                                                                                                                                                                                         | VALUES | UNITS |
|-------------------------------------------|------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-------|
| Maximum rate of rise of turned-on current | $V_{DRM} \leq 600\text{ V}$  | $T_J = T_J$ maximum, $V_{DM} = \text{Rated } V_{DRM}$<br>Gate pulse = 20 V, 15 Ω, $t_p = 6\text{ μs}$ , $t_r = 0.1\text{ μs}$ maximum<br>$I_{TM} = (2 \times \text{rated } dI/dt)\text{ A}$             | 200    | A/μs  |
|                                           | $V_{DRM} \leq 800\text{ V}$  |                                                                                                                                                                                                         | 180    |       |
|                                           | $V_{DRM} \leq 1000\text{ V}$ |                                                                                                                                                                                                         | 160    |       |
|                                           | $V_{DRM} \leq 1600\text{ V}$ |                                                                                                                                                                                                         | 150    |       |
| Typical turn-on time                      | $t_{gt}$                     | $T_J = 25\text{ °C}$ ,<br>at rated $V_{DRM}/V_{RRM}$ , $T_J = 125\text{ °C}$                                                                                                                            | 0.9    | μs    |
| Typical reverse recovery time             | $t_{rr}$                     | $T_J = T_J$ maximum,<br>$I_{TM} = I_{T(AV)}$ , $t_p > 200\text{ μs}$ , $dI/dt = -10\text{ A/μs}$                                                                                                        | 4      |       |
| Typical turn-off time                     | $t_q$                        | $T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$ , $t_p > 200\text{ μs}$ , $V_R = 100\text{ V}$ ,<br>$dI/dt = -10\text{ A/μs}$ , $dV/dt = 20\text{ V/μs}$ linear to 67 % $V_{DRM}$ ,<br>gate bias 0 V to 100 W | 110    |       |

**Note**

- $t_q = 10\text{ μs}$  up to 600 V,  $t_q = 30\text{ μs}$  up to 1600 V available on special request

**BLOCKING**

| PARAMETER                                          | SYMBOL  | TEST CONDITIONS                                     | VALUES             | UNITS |
|----------------------------------------------------|---------|-----------------------------------------------------|--------------------|-------|
| Maximum critical rate of rise of off-state voltage | $dV/dt$ | $T_J = T_J$ maximum linear to 100 % rated $V_{DRM}$ | 100                | V/μs  |
|                                                    |         | $T_J = T_J$ maximum linear to 67 % rated $V_{DRM}$  | 300 <sup>(1)</sup> |       |

**Note**

- <sup>(1)</sup> Available with:  $dV/dt = 1000\text{ V/μs}$ , to complete code add S90 i.e. 16RIA120S90



| TRIGGERING                          |                    |                                                                         |                                                                                                                                                       |        |       |
|-------------------------------------|--------------------|-------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-------|
| PARAMETER                           | SYMBOL             | TEST CONDITIONS                                                         |                                                                                                                                                       | VALUES | UNITS |
| Maximum peak gate power             | P <sub>GM</sub>    | T <sub>J</sub> = T <sub>J</sub> maximum                                 |                                                                                                                                                       | 8.0    | W     |
| Maximum average gate power          | P <sub>G(AV)</sub> |                                                                         |                                                                                                                                                       | 2.0    |       |
| Maximum peak positive gate current  | I <sub>GM</sub>    | T <sub>J</sub> = T <sub>J</sub> maximum                                 |                                                                                                                                                       | 1.5    | A     |
| Maximum peak negative gate voltage  | -V <sub>GM</sub>   | T <sub>J</sub> = T <sub>J</sub> maximum                                 |                                                                                                                                                       | 10     | V     |
| DC gate current required to trigger | I <sub>GT</sub>    | T <sub>J</sub> = - 65 °C                                                | Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied                          | 90     | mA    |
|                                     |                    | T <sub>J</sub> = 25 °C                                                  |                                                                                                                                                       | 60     |       |
|                                     |                    | T <sub>J</sub> = 125 °C                                                 |                                                                                                                                                       | 35     |       |
| DC gate voltage required to trigger | V <sub>GT</sub>    | T <sub>J</sub> = - 65 °C                                                |                                                                                                                                                       | 3.0    | V     |
|                                     |                    | T <sub>J</sub> = 25 °C                                                  |                                                                                                                                                       | 2.0    |       |
|                                     |                    | T <sub>J</sub> = 125 °C                                                 |                                                                                                                                                       | 1.0    |       |
| DC gate current not to trigger      | I <sub>GD</sub>    | T <sub>J</sub> = T <sub>J</sub> maximum, V <sub>DRM</sub> = Rated value |                                                                                                                                                       | 2.0    | mA    |
| DC gate voltage not to trigger      | V <sub>GD</sub>    | T <sub>J</sub> = T <sub>J</sub> maximum, V <sub>DRM</sub> = Rated value | Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied | 0.2    | V     |

| THERMAL AND MECHANICAL SPECIFICATIONS                    |                                   |                                                |                  |           |          |
|----------------------------------------------------------|-----------------------------------|------------------------------------------------|------------------|-----------|----------|
| PARAMETER                                                | SYMBOL                            | TEST CONDITIONS                                | VALUES           |           | UNITS    |
| Maximum operating junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub> |                                                | - 65 to 125      |           | °C       |
| Maximum thermal resistance, junction to case             | R <sub>thJC</sub>                 | DC operation                                   | 0.86             |           | K/W      |
| Maximum thermal resistance, case to heatsink             | R <sub>thCS</sub>                 | Mounting surface, smooth, flat and greased     | 0.35             |           |          |
|                                                          |                                   |                                                | TO NUT           | TO DEVICE |          |
| Mounting torque                                          |                                   | Lubricated threads<br>(Non-lubricated threads) | 20 (27.5)        | 25        | lbf · in |
|                                                          |                                   |                                                | 0.23 (0.32)      | 0.29      | kgf · m  |
|                                                          |                                   |                                                | 2.3 (3.1)        | 2.8       | N · m    |
| Approximate weight                                       |                                   |                                                | 14               |           | g        |
|                                                          |                                   |                                                | 0.49             |           | oz.      |
| Case style                                               |                                   | See dimensions - link at the end of datasheet  | TO-208AA (TO-48) |           |          |

| $\Delta R_{thJC}$ CONDUCTION |                       |                        |                     |       |
|------------------------------|-----------------------|------------------------|---------------------|-------|
| CONDUCTION ANGLE             | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS     | UNITS |
| 180°                         | 0.21                  | 0.15                   | $T_J = T_J$ maximum | K/W   |
| 120°                         | 0.25                  | 0.25                   |                     |       |
| 90°                          | 0.31                  | 0.34                   |                     |       |
| 60°                          | 0.45                  | 0.47                   |                     |       |
| 30°                          | 0.76                  | 0.76                   |                     |       |

**Note**

- The table above shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC

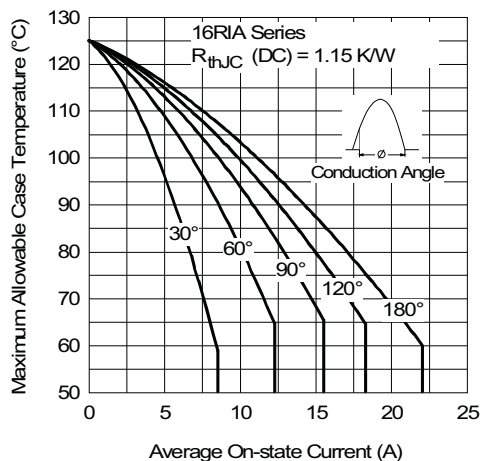


Fig. 1 - Current Ratings Characteristics

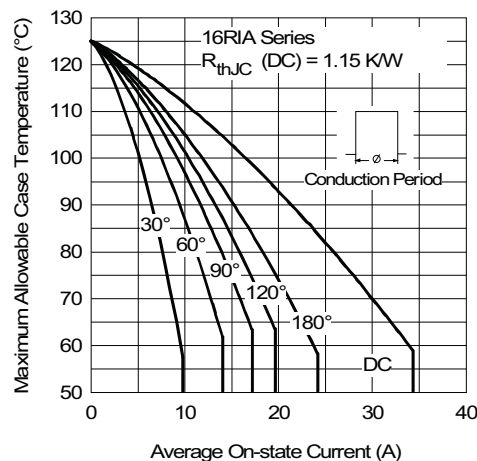


Fig. 2 - Current Ratings Characteristics

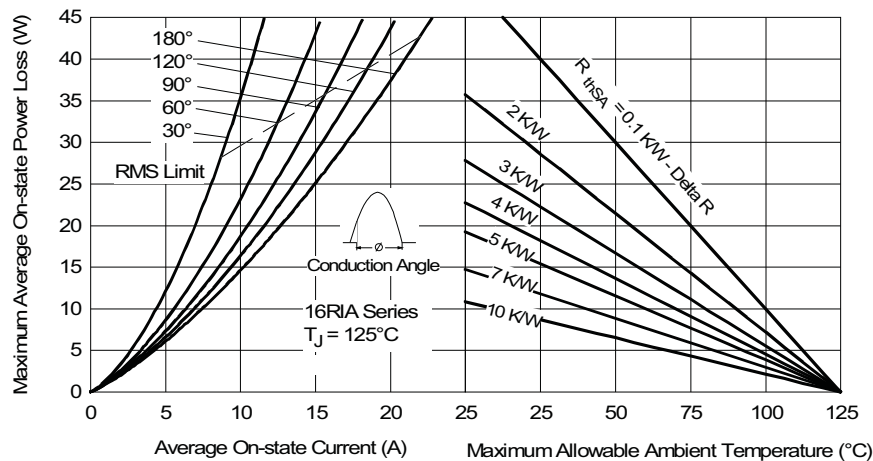


Fig. 3 - On-State Power Loss Characteristics

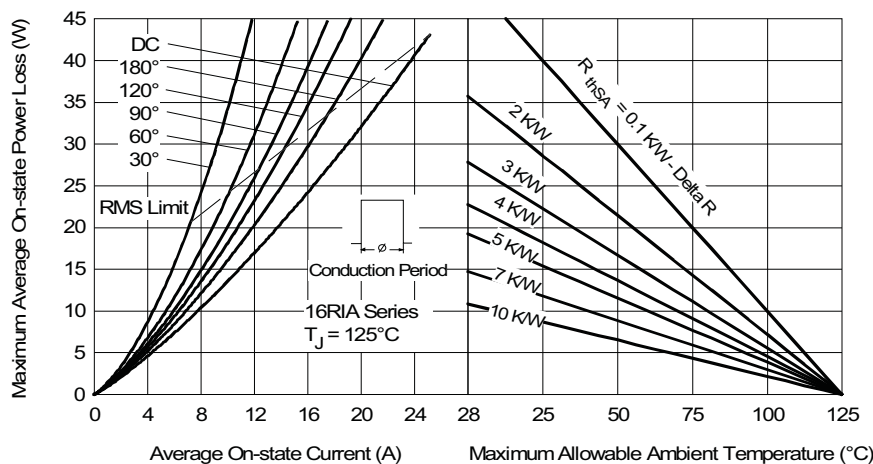


Fig. 4 - On-State Power Loss Characteristics

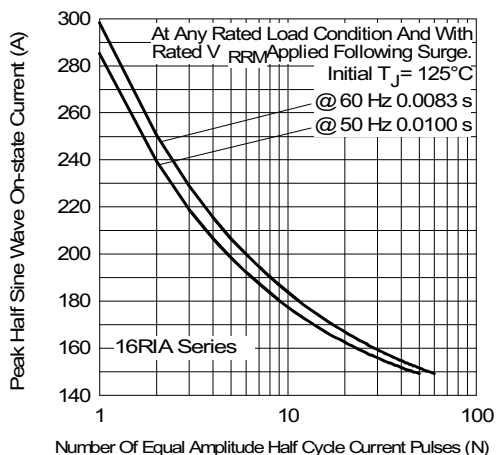


Fig. 5 - Maximum Non-Repetitive Surge Current

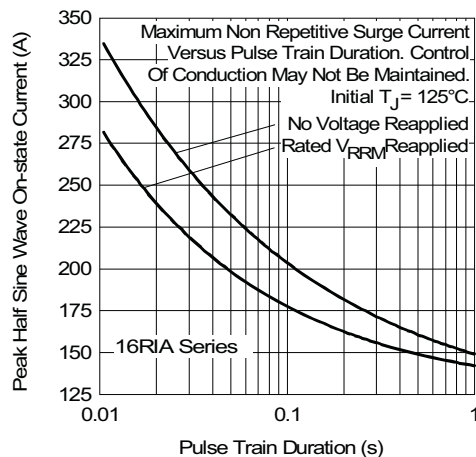


Fig. 6 - Maximum Non-Repetitive Surge Current

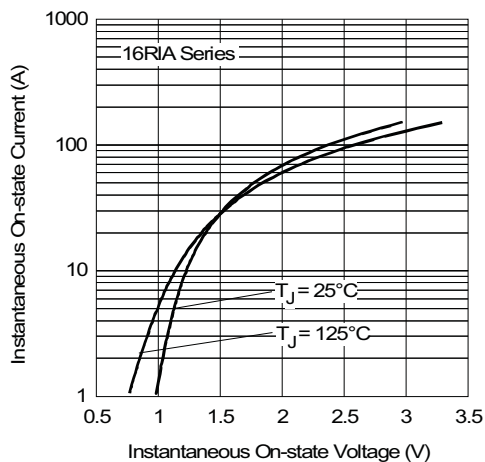


Fig. 7 - Forward Voltage Drop Characteristics

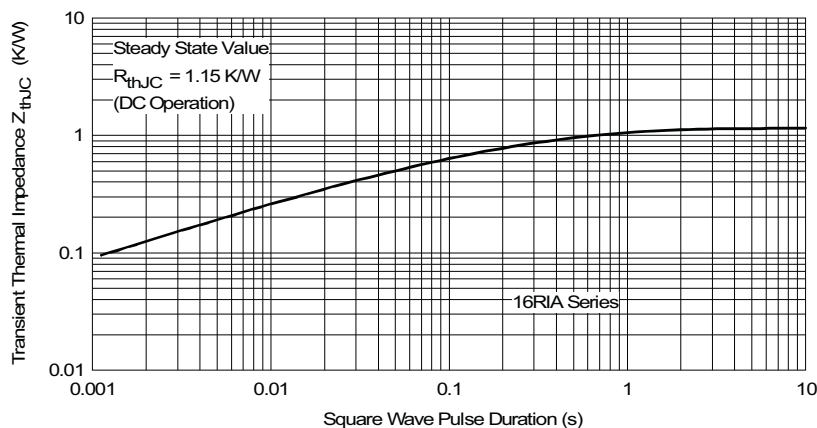


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

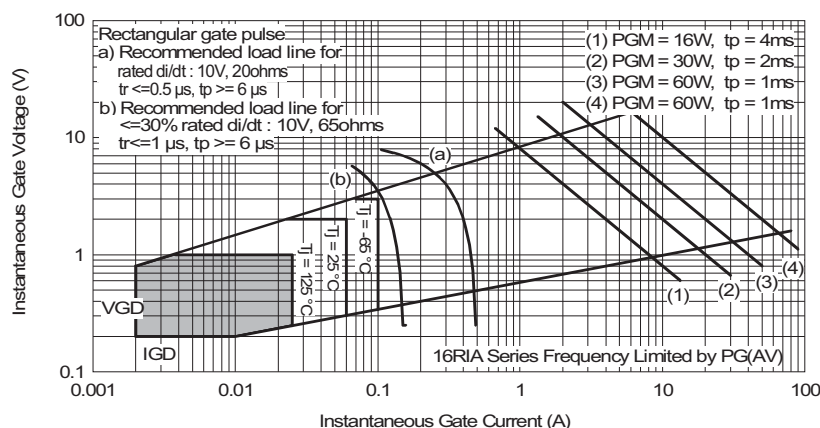


Fig. 9 - Gate Characteristics

## ORDERING INFORMATION TABLE

| Device code | 16 | RIA | 120 | M | S90 |
|-------------|----|-----|-----|---|-----|
|             | ①  | ②   | ③   | ④ | ⑤   |

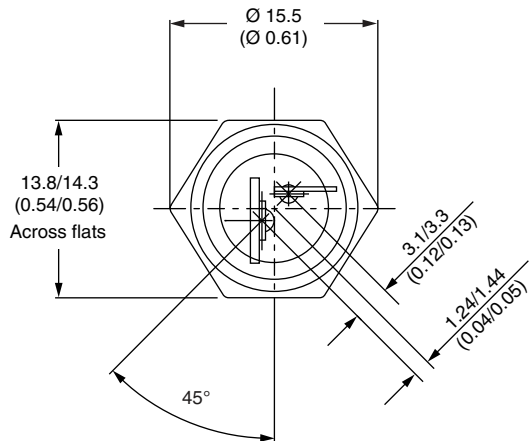
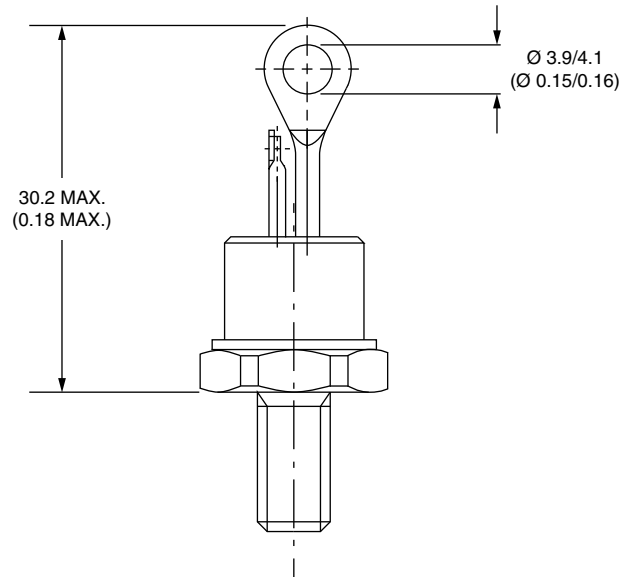
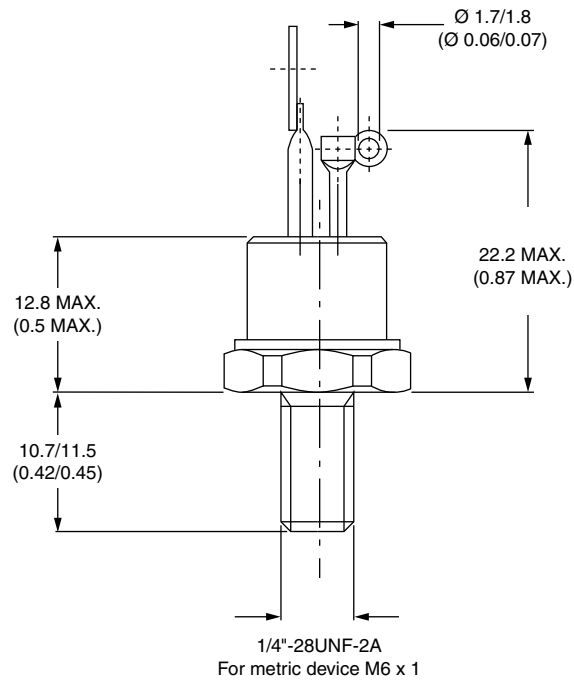
- 1** - Current code
- 2** - Essential part number
- 3** - Voltage code  $\times 10 = V_{RRM}$  (see Voltage Ratings table)
- 4** - None = Stud base TO-208AA (TO-48) 1/4" 28UNF-2A  
M = Stud base TO-208AA (TO-48) M6 x 1
- 5** - Critical  $dV/dt$ :  
None = 300 V/ $\mu s$  (standard value)  
S90 = 1000 V/ $\mu s$  (special selection)

### LINKS TO RELATED DOCUMENTS

|            |                                                                        |
|------------|------------------------------------------------------------------------|
| Dimensions | <a href="http://www.vishay.com/doc?95333">www.vishay.com/doc?95333</a> |
|------------|------------------------------------------------------------------------|

## TO-208AA (TO-48)

**DIMENSIONS** in millimeters (inches)





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